

KEPS50500 Electrical Characteristics

Unless otherwise specified: $18V < V_{IN} < 50V$, $0A < I_{OUT} < 10A$, $-55^{\circ}C < T_{CASE} < 100^{\circ}C$

Parameter	Sym	Conditions	Min	Typ	Max	Unit
Input Specifications						
Input Voltage Range	V_{IN}		18	28	50	V_{DC}
Input dV/dt	V_{INDVDT}	$V_{IN}=50V$			1	$V/\mu S$
Input Undervoltage Turn-on	V_{UVON}	$I_O=10A$	15.4	16.3	17.1	V_{DC}
Input Undervoltage Turn-off	V_{UVOFF}	$I_O=10A$	14.9	15.8	16.6	V_{DC}
Input Undervoltage hysteresis	V_{UVH}	$I_O=10A$		0.5		V_{DC}
Input Overvoltage Turn-on	V_{OVON}	$I_O=10A$	47.3	48.4	49.6	V_{DC}
Input Overvoltage Turn-off	V_{OVOFF}	$I_O=10A$	48.6	49.8	51	V_{DC}
Input Overvoltage hysteresis	V_{OVH}	$I_O=10A$		1.4		V_{DC}
Input Quiescent Current	I_Q	$V_{IN}=28V$, $ENABLE=0V$				mApp
Input Idling Power	P_{IDLE}	$V_{IN}=28V$, $I_O=10A$				W
Input Standby Power	P_{SBY}	$V_{IN}=28V$, $ENABLE=0V$				W
Input Current Full Load	I_{IN}	$T_{CASE}=100^{\circ}C$, $I_O=10A$, $\eta=86\%$ typical, $V_{IN}=28V$				A_{DC}
Input Reflected Ripple Voltage	I_{INRR}	$L_{IN}=0.47\mu H$, $C_{IN}=100\mu F$ 63V electrolytic, + 2x4.7 μF 50V X7R				mApp
Recommended Ext Input Cap.	C_{IN}	100 μF 63V electrolytic, + 2x4.7 μF 50V X7R		109.4		μF
Output Specifications						
Output Voltage Set Point	V_{OUT}	$I_{OUT}=5A$				V_{DC}
Total Output Accuracy	V_{OA}	$0^{\circ}C < T_{CASE} < 100^{\circ}C$				%
		$-55^{\circ}C < T_{CASE} < 0^{\circ}C$				%
Output Voltage Trim Range	V_{OADI}					%
Output Current Range	I_{OUT}					A_{DC}
Overcurrent Protection	I_{OCP}					A_{DC}
Efficiency - Full Load	η_{FL}	$T_{CASE} = 100^{\circ}C$, $V_{IN}=28V$				%
Efficiency - Half Load	η_{HL}	$T_{CASE} = 100^{\circ}C$, $V_{IN}=28V$				%
Output OVP Setpoint	V_{OVP}	Continuous Control				V_{DC}
Output Ripple Voltage	V_{ORPP}	$C_{OUT}=6x10 \mu F$ 10V X7R DC-20MHz				mV _{PP}
Switching Frequency	f_{SW}			500		kHz
Output Turn On Delay time	t_{ONDLY}	$V_{IN}= V_{UVON}$ to $ENABLE=5V$; V_{IN} rise time <1ms				ms
Output Turn Off Delay time	t_{OFFDLY}	$V_{IN}= V_{UVOFF}$ V_{UVON} to $ENABLE < 2.35V$				μS
Soft Start Ramp Time	t_{SS}					μS
Maximum Load Capacitance	C_{OUT}	$C_{OUT} = Al$ electrolytic				μF
Load Transient Deviation	V_{ODV}	$I_{OUT}=\%50$ step 0.1A/ μS $C_{OUT}=6x10 \mu F$ 10V X7R				mV
Load Transient Recovery Time	T_{OVR}	$I_{OUT}=\%50$ step 0.1A/ μS $C_{OUT}=6x10 \mu F$ 10V X7R $V_{OUT}\leq \%1$				μS
Maximum Output Power	P_{OUT}					W
Absolute Maximum Output Ratings						
Name		Ratings				
+OUT to -OUT		0 to 6V _{DC}				
Continuous Output Current		10A _{DC}				
Peak Output Current		20A _{DC}				

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
ENABLE PIN						
DC Voltage reference Output	V _{ERO}		4.9	5	5.1	V _{DC}
Output Current Limit	I _{ECL}					mA _{DC}
Startup CurrenT Limit	I _{ESL}					μA _{DC}
Module Enable Voltage	V _{EME}		2.53			V _{DC}
Module Disable Voltage	V _{EMD}				2.47	V _{DC}
Disable Hysteresis	V _{EDH}			600		mV
Enable Delay Time	t _{ED}					μS
Disable Delay Time	t _{DD}					μS
Maximum Capacitance	C _{EC}			1500		pF
Maximum external Toggle Time	f _{EXT}			1		Hz
TRIM PIN						
Trim VOLTage Reference	V _{REF}		1.22	1.25	1.27	V _{DC}
Internal Capacitance	C _{REFI}					°K
External Capacitance	C _{REF}					μF
Internal Resistance	R _{REFI}			8.2		kΩ
TM(Temperature Monitor)						
Temperature Coefficient	TM _{TC}			10		mV/°K
Temperature Full Range Accurary	TM _{ACC}		-5		5	°K
Drive Capability	I _{TM}			1		mA
TM Outpt Setting	V _{TM}	Ambient temperature 273°K		2.73		V
Thermal Specification						
Junction Temperature Shutdown	T _{MAX}		125	129	135	°C
Junction to Case Thermal Impedance	θ _{J-C}					°C/W
Junction to Ambient Thermal Impedance	θ _{J-A}			12		°C/W
Soldering						
Recommended Soldering Temperature					230	°C
Peak Temperature During Reflow						°C

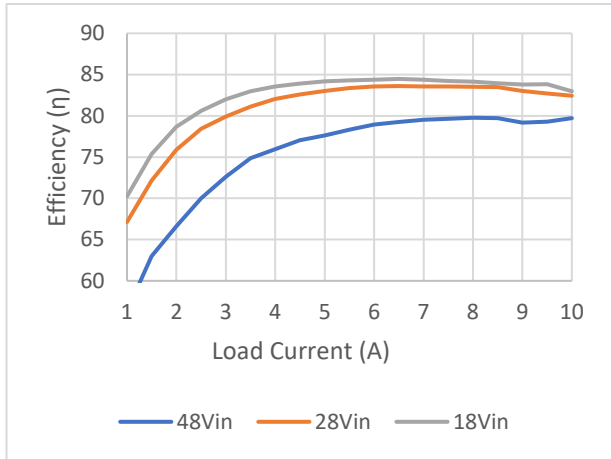


Figure 1 :Conversion Efficiency

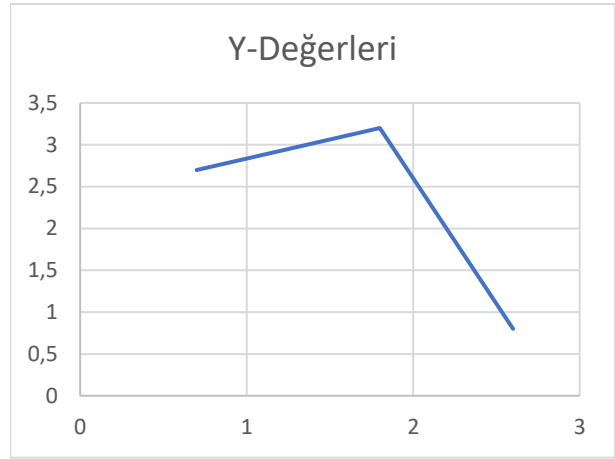


Figure 4: Load current vs Ambient Temp (With 11mm Heatsink)

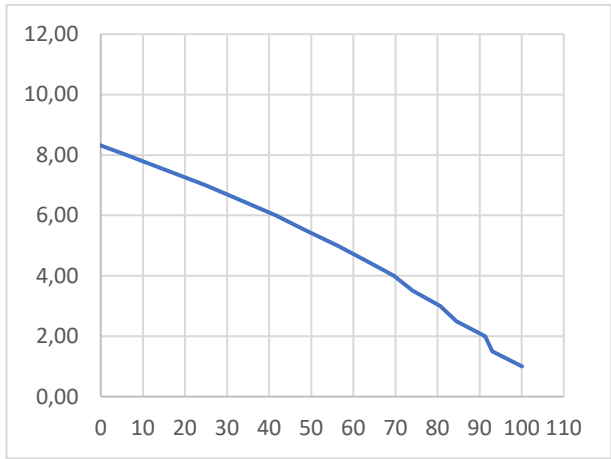


Figure 2 : Load current vs Ambient Temp (Without Heatsink)

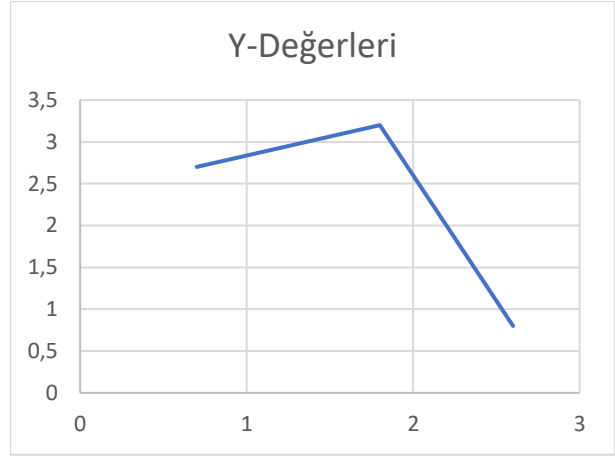


Figure 5 :Start up, VIN=16V, IOU=10A, COU 6x10uF X7R Ceramic

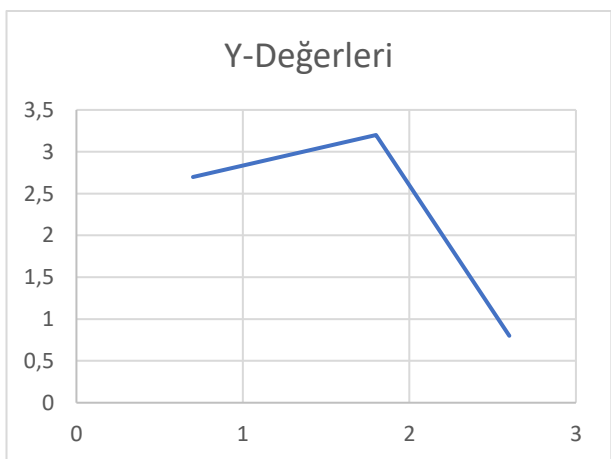


Figure 3: Load current vs Ambient Temp (With 6.33mm Heatsink)

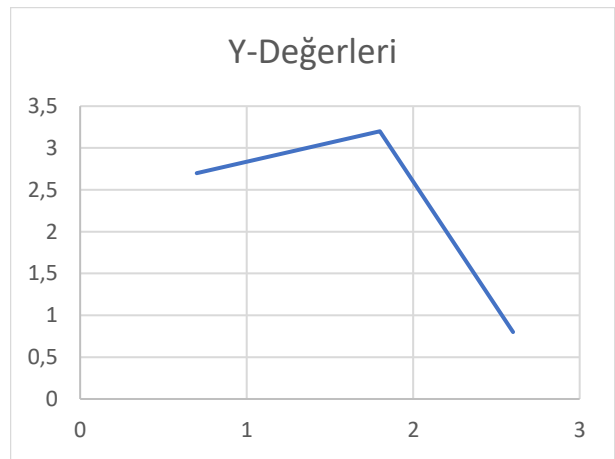


Figure 6 :Start up, VIN=28V, IOU=10A, COU 6x10uF X7R Ceramic

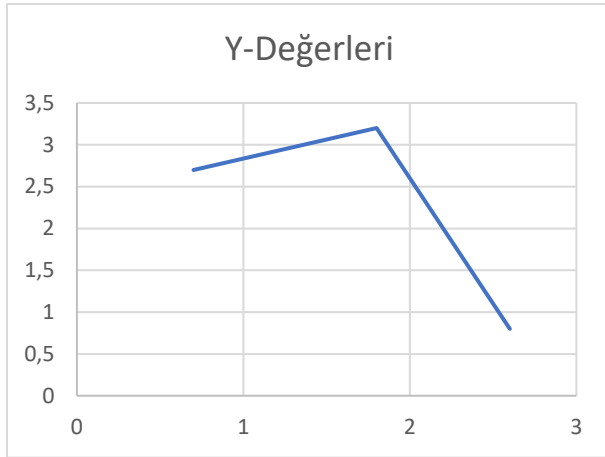


Figure 7 ::Start up, $V_{IN}=50V$, $I_{OUT}=10A$, C_{OUT} 6x10uF X7R Ceramic

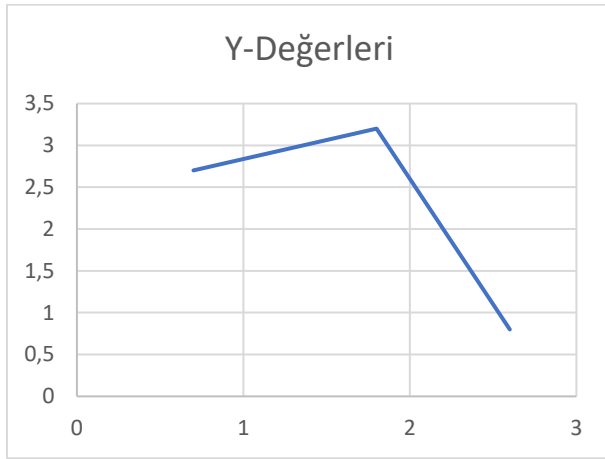


Figure 8 :Transient Response ($V_{IN}=28V$, $I_{OUT}= 5-10A$, $0.1A/\mu s$, $C_{OUT}=6x10\mu F$ X7R Ceramic)

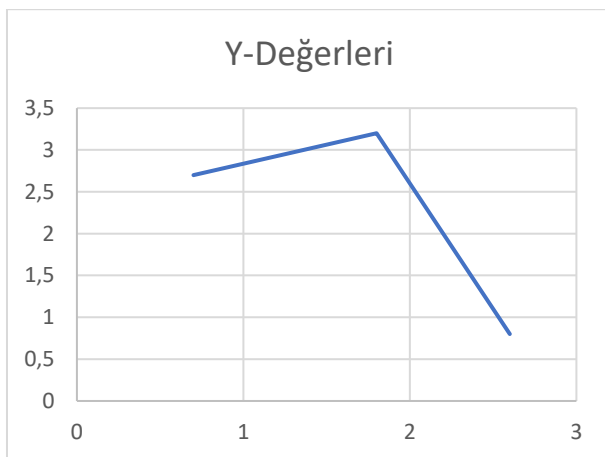


Figure 9 :Output ripple ($V_{IN}=28V$, $I_{OUT}=10A$, $C_R, C_{OUT}=6x10\mu F$ X7R Ceramic)